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Contact us

Tel: +86-755-8981 8866 Fax: +86-755-8427 6832

Email & Skype: info@chipsmall.com Web: www.chipsmall.com

Address: A1208, Overseas Decoration Building, #122 Zhenhua RD., Futian, Shenzhen, China



CND0313A

Infrared Optical Module (IrDA)

Infrared data link for cellular phones, peripheral devices

■ Features

- Compliant with IrDA Ver.1.4
- Light emitting function for remote controller
- Corresponding low I/O (interface) voltage: 1.5 V
- Corresponding reflow solder (260°C)
- Ultra-small side view package (1.45 mm × 6.7 mm × 2.15 mm)

■ Type

- GaAlAs LED + IC + PIN Photodiode

■ Absolute Maximum Ratings $T_a = 25^{\circ}\text{C} \pm 3^{\circ}\text{C}$

Parameter	Symbol	Rating	Unit
Operating supply voltage	V_{CC}	-0.5 to +3.8	V
LED operating supply voltage	V_{LEDA}	-0.5 to +7.0	V
Input/output supply voltage	V_{IO}	-0.5 to +3.8	V
TX Input voltage	V_{TX}	-0.5 to +3.8	V
Shutdown input voltage	V_{SD}	-0.5 to +3.8	V
LED operating supply current *	I_{LEDA}	300	mA
Operating ambient temperature	T_{opr}	-20 to +70	°C
Storage temperature	T_{stg}	-30 to +85	°C

Note) *: $t_w \leq 90 \mu\text{s}$, Duty $\leq 25\%$

■ Operating Condition

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Operating supply voltage	V_{CC}		2.5	2.85	3.3	V
LED operating supply voltage	V_{LEDA}		3.0		4.5	V
Input/output supply voltage	V_{IO}		1.5	1.85	V_{CC}	V

Electrical-Optical Characteristics $V_{LEDA} = 3.0 \text{ V to } 4.5 \text{ V}$, $V_{CC} = 2.85 \text{ V}$, $V_{IO} = 1.85 \text{ V}$, $T_a = 25^\circ\text{C} \pm 3^\circ\text{C}$

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Shut down supply current *Fig. 1	I_{CCSD}	$V_{TXD} = 0.5 \text{ V}$, $V_{IO} \geq V_{SD} \geq V_{IO} - 0.5 \text{ V}$ (SD = High)	—	0.01	0.2	μA
High level supply current (Idle) *Fig. 1	I_{CCH}	(FIR mode / RC mode) $E_I = 0 \text{ mW/cm}^2$, $V_{TXD} = 0.5 \text{ V}$, $V_{SD} \leq 0.5 \text{ V}$	—	580	800	μA
		(SIR mode) $E_I = 0 \text{ mW/cm}^2$, $V_{TXD} = 0.5 \text{ V}$, $V_{SD} \leq 0.5 \text{ V}$	—	300	400	
Low level supply current (Active) *Fig. 1	I_{CCL}	(FIR mode / RC mode) $E_I = 9.0 \text{ mW/cm}^2$, $V_{TXD} = 0.5 \text{ V}$, $V_{SD} \leq 0.5 \text{ V}$	—	980	1270	μA
		(SIR mode) $E_I = 9.0 \text{ mW/cm}^2$, $V_{TXD} = 0.5 \text{ V}$, $V_{SD} \leq 0.5 \text{ V}$	—	350	460	
TX High level supply current (Active) *Fig. 1	I_{CCTXH}	(FIR mode / RC mode) $V_{IO} \geq V_{TXD} \geq V_{IO} - 0.5 \text{ V}$ (TXD = High) $E_I = 0 \text{ mW/cm}^2$, $V_{SD} \leq 0.5 \text{ V}$	—	1200	1560	μA
		(SIR mode) $V_{IO} \geq V_{TXD} \geq V_{IO} - 0.5 \text{ V}$ (TXD = High) $E_I = 0 \text{ mW/cm}^2$, $V_{SD} \leq 0.5 \text{ V}$	—	600	780	
High level input/output supply current (Idle) *Fig. 1	I_{IOH}	(FIR mode / RC mode) $E_I = 0 \text{ mW/cm}^2$, $V_{TXD} = 0.5 \text{ V}$, $V_{SD} \leq 0.5 \text{ V}$	0	0	5	μA
		(SIR mode) $E_I = 0 \text{ mW/cm}^2$, $V_{TXD} = 0.5 \text{ V}$, $V_{SD} \leq 0.5 \text{ V}$	0	0	5	
Low level input/output supply current (Active) *Fig. 1	I_{IOL}	(FIR mode / RC mode) $E_I = 9.0 \text{ mW/cm}^2$, $V_{TXD} = 0.5 \text{ V}$, $V_{SD} \leq 0.5 \text{ V}$	—	360	470	μA
		(SIR mode) $E_I = 9.0 \text{ mW/cm}^2$, $V_{TXD} = 0.5 \text{ V}$, $V_{SD} \leq 0.5 \text{ V}$	—	100	130	
TX High level input/output supply current (Active) *Fig. 1	I_{IOTXH}	(FIR mode / RC mode) $V_{IO} \geq V_{TXD} \geq V_{IO} - 0.5 \text{ V}$ (TXD = High) $E_I = 0 \text{ mW/cm}^2$, $V_{SD} \leq 0.5 \text{ V}$	—	80	120	μA
		(SIR mode) $V_{IO} \geq V_{TXD} \geq V_{IO} - 0.5 \text{ V}$ (TXD = High) $E_I = 0 \text{ mW/cm}^2$, $V_{SD} \leq 0.5 \text{ V}$	—	40	60	
SD High level input voltage	V_{IHSD}		$V_{IO} - 0.5$	—	$V_{IO} + 0.3$	V
SD Low level input voltage	V_{ILSD}		0 -0.3	—	0.5	V
Maximum reception distance *Fig. 1, 4	L_{max}	$V_{SD} \leq 0.5 \text{ V}$ $\theta_T = 0^\circ \pm 15^\circ$ LEDie = 3.6 mW/sr (SIR mode) LEDie = 9 mW/sr (FIR mode)	20	—	—	cm
RC maximum reception distance *Fig. 1, 10	L_{maxR}	$V_{LEDA} = 3.0 \text{ V}$, $V_{SD} \leq 0.5 \text{ V}$ $\theta_T = 0^\circ \pm 15^\circ$, Carrier duty = 1/3 940 nm Radiant intensity ratio = 57.5 % RC Receiver sensitivity *2 = 0.05 $\mu\text{W/cm}^2$	5.14	—	—	m
Data Rates *1	—		0.0096	—	4.0	Mbps

Note) *1: Fully Compliant to IrDA1.4 Low Power Specification from 9.6 kbps to 115.2 kbps, 4 Mbps.

*2: Definition of RC receiver sensitivity

RC receiver sensitivity is adjusted so that RC transfer distance is 4 m at transmitter LED radiant intensity = 8 mW/sr, peak wave length = 940 nm and duty = 50 %, where irradiance is 0.05 $\mu\text{W/cm}^2$.

■ Electrical-Optical Characteristics (continued) $V_{LEDA} = 3.0 \text{ V to } 4.5 \text{ V}$, $V_{CC} = 2.85 \text{ V}$, $V_{IO} = 1.85 \text{ V}$, $T_a = 25^\circ\text{C} \pm 3^\circ\text{C}$

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Transmitter						
Peak emission wavelength *Fig. 1	λ_p	(FIR mode / RC mode) $V_{LEDA} = 3.2 \text{ V}$, $V_{SD} \leq 0.5 \text{ V}$, Duty1/4	880	890	900	nm
		(SIR mode) $V_{LEDA} = 3.2 \text{ V}$, $V_{SD} \leq 0.5 \text{ V}$, Duty3/16	875	885	900	
LED operating supply current *Fig. 1	I_{LEDA}	(FIR Mode/RC Mode) $V_{LEDA} = 4.3 \text{ V}$, $V_{SD} \leq 0.5 \text{ V}$, Duty1/4	165	207	248	mA
		(FIR Mode/RC Mode) $V_{LEDA} = 3.0 \text{ V}$, $V_{SD} \leq 0.5 \text{ V}$, Duty1/4	160	200	240	
		(SIR Mode) $V_{LEDA} = 4.3 \text{ V}$, $V_{SD} \leq 0.5 \text{ V}$, Duty3/16	70	91	109	
		(SIR Mode) $V_{LEDA} = 3.0 \text{ V}$, $V_{SD} \leq 0.5 \text{ V}$, Duty3/16	69	90	108	
Center radiant intensity *3	$\theta_T = 0$ *Fig. 1, 2	(FIR Mode/RC Mode) $V_{LEDA} = 3.0 \text{ V}$, $V_{SD} \leq 0.5 \text{ V}$, Duty1/4	30	70	105	mW/sr
		(SIR Mode) $V_{LEDA} = 3.0 \text{ V}$, $V_{SD} \leq 0.5 \text{ V}$, Duty3/16	15	35	52	
	$\theta_T = \pm 15$ *Fig.1, 2, 10	(FIR Mode/RC Mode) $V_{LEDA} = 3.0 \text{ V}$, $V_{SD} \leq 0.5 \text{ V}$, Duty1/4	23	38	57	mW/sr
		(SIR Mode) $V_{LEDA} = 3.0 \text{ V}$, $V_{SD} \leq 0.5 \text{ V}$, Duty3/16	7	19	28	
TX high level input voltage	$V_{IH(TX)}$		$V_{IO} - 0.5$	—	$V_{CC} + 0.3$	V
TX low level input voltage	$V_{IL(TX)}$		0 -0.3	—	0.5	V
TX pulse width (SIR) *Fig. 1, 8	$t_{WT(SIR)}$	Bit Rate = 115.2 kbps, $V_T = 1/2 \times V_{IO}$	—	1.6	—	μs
TX pulse width (FIR) *Fig. 1, 8	$t_{WT(FIR)}$	Bit Rate = 4.0 Mbps, $V_T = 1/2 \times V_{IO}$	—	125	—	ns
Optical pulse width (FIR1) *Fig. 1, 3	$t_{WO(FIR1)}$	$V_{SD} \leq 0.5 \text{ V}$, TXD $t_r / t_f \leq 20 \text{ ns}$, $t_w = 125 \text{ ns} \pm 1 \text{ ns}$, (Single pulse)	115	125	135	ns
Optical pulse width (FIR2) *Fig. 1, 3	$t_{WO(FIR2)}$	$V_{SD} \leq 0.5 \text{ V}$, TXD $t_r / t_f \leq 20 \text{ ns}$, $t_w = 250 \text{ ns} \pm 1 \text{ ns}$, (Double pulse)	240	250	260	ns
TX half-angle	θ_T		± 15	—	—	$^\circ$
Rise time *Fig. 1, 3	t_r	$R_L = 50 \Omega$	—	—	40	ns
Fall time *Fig. 1, 3	t_f	$R_L = 50 \Omega$	—	—	40	ns
TX wake up time *Fig. 5	t_{TWU}		200	—	1000	μs
Intensity delay time *Fig. 1, 3	I_{DT}		—	—	200	ns
Maximum pulse width	$t_{WLEDmax}$	TXD = Low \rightarrow High	20	50	100	μs
Overshoot	O_S		—	—	25	%

Note) *3: Eye-Safety IEC60825-1 Class1 Eye safe

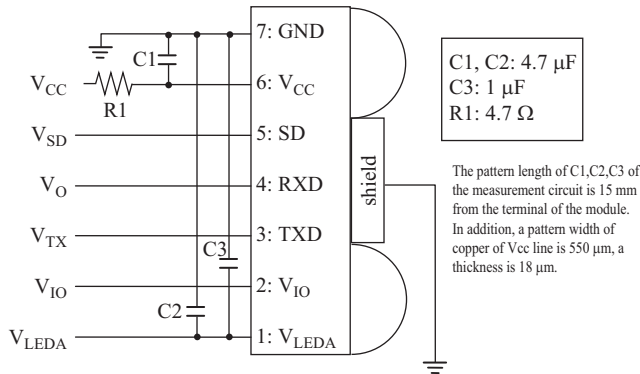
■ Electrical-Optical Characteristics (continued) $V_{LEDA} = 3.0 \text{ V to } 4.5 \text{ V}$, $V_{CC} = 2.85 \text{ V}$, $V_{IO} = 1.85 \text{ V}$, $T_a = 25^\circ\text{C} \pm 3^\circ\text{C}$

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Receiver						
Minimum input irradiance *Fig. 1	$E_{I\min1}$	(SIR mode) Bit Rate = 115.2 kbps, $V_{SD} \leq 0.5 \text{ V}$, $\theta_T = 0^\circ \pm 15^\circ$	—	—	9.0	$\mu\text{W}/\text{cm}^2$
	$E_{I\min2}$	(FIR Mode) Bit Rate = 4.0 Mbps, $V_{SD} \leq 0.5 \text{ V}$, $\theta_T = 0^\circ \pm 15^\circ$	—	—	22.5	
Maximum input irradiance *Fig. 1	$E_{I\text{mix}}$	$V_{SD} \leq 0.5 \text{ V}$, $\theta_T = 0^\circ \pm 15^\circ$	500	—	—	mW/cm^2
RX high level output voltage *Fig. 1	$V_{OH(RX)}$	Non signal condition $E_I = 0$ $I_{OH} = -200 \mu\text{A}$, $V_{SD} \leq 0.5 \text{ V}$	$V_{IO} - 0.3$	—	V_{IO}	V
RX low level output voltage *Fig. 1	$V_{OL(RX)}$	$I_{OL} = 1.8 \text{ mA}$, $V_{SD} \leq 0.5 \text{ V}$	0	—	0.5	V
RX half angle	θ_R		± 15	—	—	°
Output pulse width (SIR) *Fig. 1, 9	$t_{WR(SIR)}$	$V_{SD} \leq 0.5 \text{ V}$, $C_L = 15 \text{ pF}$, 9.6 kbps to 115.2 kbps	1.0	—	4.0	μs
Output pulse width (FIR1) *Fig. 1, 9	$t_{WR(FIR1)}$	$V_{SD} \leq 0.5 \text{ V}$, $C_L = 15 \text{ pF}$, 4 Mbps, $t_W = 125 \text{ ns} \pm 10 \text{ ns}$ (Single pulse)	85	—	165	ns
Output pulse width (FIR2) *Fig. 1, 9	$t_{WR(FIR2)}$	$V_{SD} \leq 0.5 \text{ V}$, $C_L = 15 \text{ pF}$, 4 Mbps, $t_W = 250 \text{ ns} \pm 10 \text{ ns}$ (Double pulse)	195	—	290	ns
RX wake up time *Fig. 1, 6	t_{Rwu}	$V_{SD} \leq 0.5 \text{ V}$, $E_I = 17.0 \mu\text{W}/\text{cm}^2$	—	100	200	μs
Receiver latency time *Fig. 1, 7	t_L	$V_{SD} \leq 0.5 \text{ V}$, $E_I = 17.0 \mu\text{W}/\text{cm}^2$	—	100	200	μs
Rise time *Fig. 1, 9	t_r	$V_{SD} \leq 0.5 \text{ V}$, $C_L = 15 \text{ pF}$	—	10	—	ns
Fall time *Fig. 1, 9	t_f	$V_{SD} \leq 0.5 \text{ V}$, $C_L = 15 \text{ pF}$	—	10	—	ns

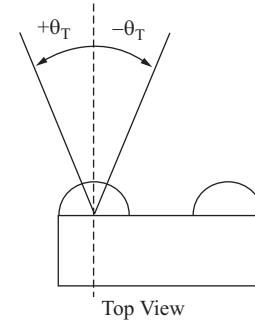
Electrical-Optical Characteristics (continued)

Note) Measurement circuit

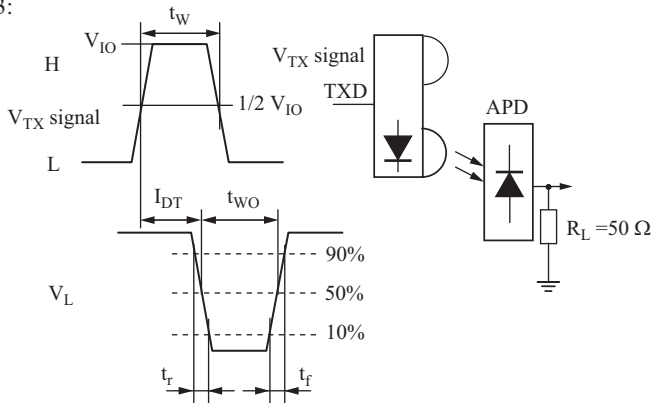
*Fig. 1:



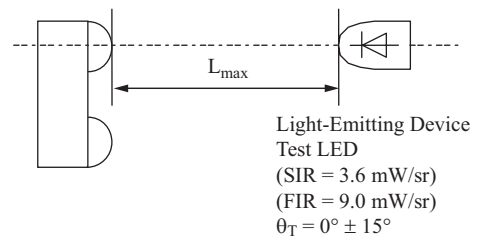
*Fig. 2:



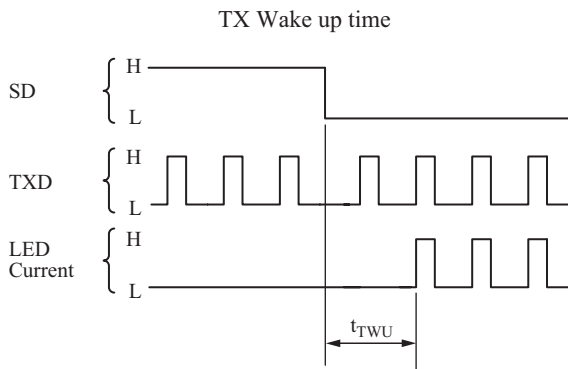
*Fig. 3:



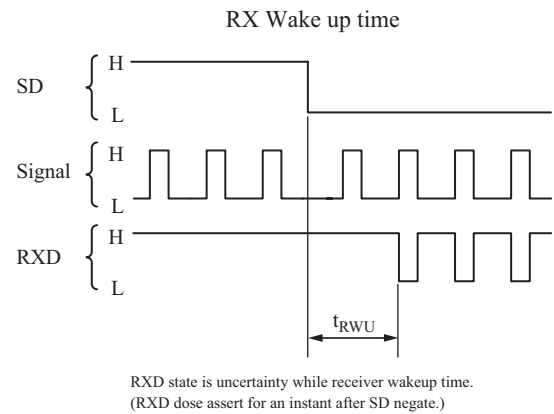
*Fig. 4:



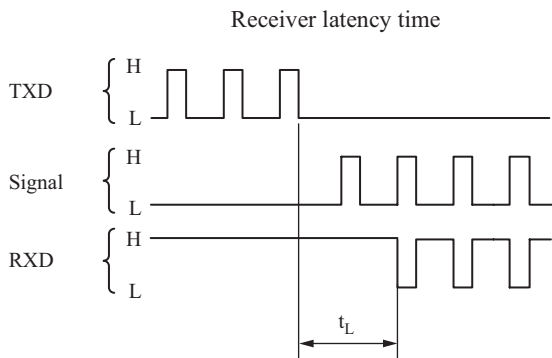
*Fig. 5:



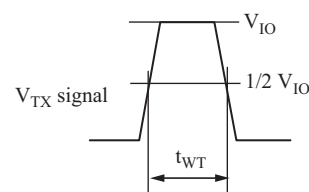
*Fig. 6:



*Fig. 7:



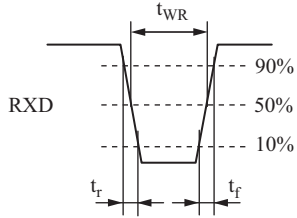
*Fig. 8:



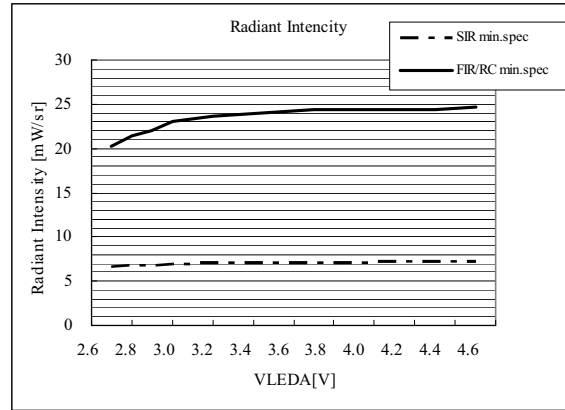
■ Electrical-Optical Characteristics (continued)

Note) Measurement circuit (continued)

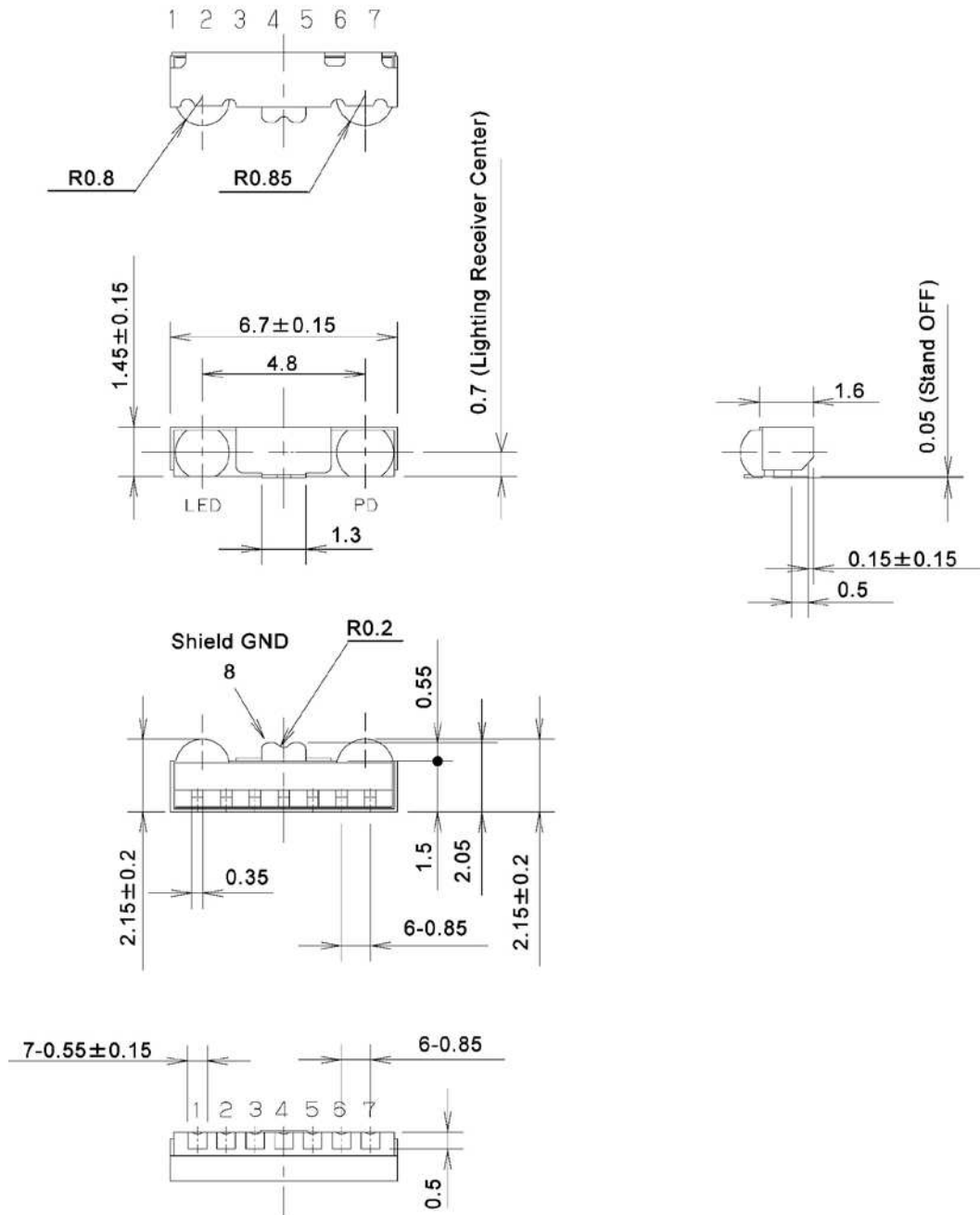
*Fig. 9:



*Fig. 10:



■ Package (Unit: mm)



• Pin name

- | | |
|---------------|---------------|
| 1. V_{LEDA} | 5. SD |
| 2. V_{IO} | 6. V_{CC} |
| 3. TXD | 7. GND |
| 4. RXD | 8. Shield GND |

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